RENESAS HD74LV4040A

12-stage Binary Counter

REJ03D0337–0200Z (Previous ADE-205-282 (Z)) Rev.2.00 Jul. 20, 2004

Description

The HD74LV4040A is a 12 stage counter. This device is incremented on the falling edge (negative transition) of the input clock, and all its output is reset to a low level by applying a logical high on its reset input. Low-voltage and high-speed operation is suitable for the battery-powered products (e.g., notebook computers), and the low-power consumption extends the battery life.

Features

- $V_{CC} = 2.0 \text{ V}$ to 5.5 V operation
- All inputs V_{IH} (Max.) = 5.5 V (@V_{CC} = 0 V to 5.5 V)
- All outputs V_0 (Max.) = 5.5 V (@V_{CC} = 0 V)
- Typical V_{OL} ground bounce < 0.8 V (@V_{CC} = 3.3 V, Ta = 25°C)
- Typical V_{OH} undershoot > 2.3 V (@V_{CC} = 3.3 V, Ta = 25°C)
- Output current $\pm 6 \text{ mA}$ (@V_{CC} = 3.0 V to 3.6 V), $\pm 12 \text{ mA}$ (@V_{CC} = 4.5 V to 5.5 V)
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LV4040AFPEL	SOP–16 pin (JEITA)	FP–16DAV	FP	EL (2,000 pcs/reel)
HD74LV4040ARPEL	SOP-16 pin (JEDEC)	FP–16DNV	RP	EL (2,500 pcs/reel)
HD74LV4040ATELL	TSSOP-16 pin	TTP–16DAV	Т	ELL (2,000 pcs/reel)

Note: Please consult the sales office for the above package availability.

Function Table

Inputs		Output
CLK	CLR	Q _n
\uparrow	L	Remains unchanged
\downarrow	L	Changed
X	Н	All outputs low

Note: H: High level

L: Low level

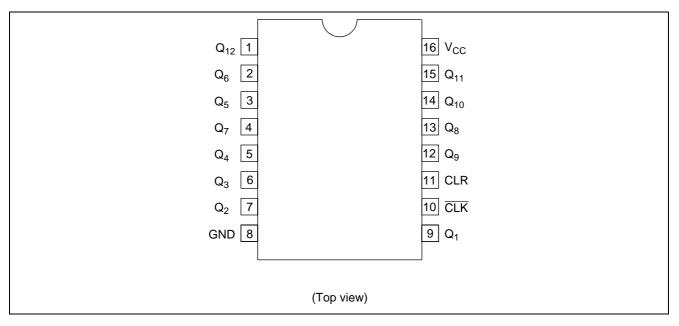
X: Immaterial

 \uparrow : Low to high transition

 \downarrow : High to low transition



Pin Arrangement



Absolute Maximum Ratings

ltem	Symbol	Ratings	Unit	Conditions
Supply voltage range	V _{CC}	–0.5 to 7.0	V	
Input voltage range*1	VI	–0.5 to 7.0	V	
Output voltage range* ^{1, 2}	Vo	–0.5 to V _{CC} + 0.5	V	Output: H or L
		–0.5 to 7.0		V _{CC} : OFF
Input clamp current	I _{IK}	-20	mA	V ₁ < 0
Output clamp current	l _{ок}	±50	mA	$V_{\rm O}$ < 0 or $V_{\rm O}$ > $V_{\rm CC}$
Continuous output current	lo	±25	mA	$V_{\rm O}$ = 0 to $V_{\rm CC}$
Continuous current through V_{CC} or GND	I_{CC} or I_{GND}	±50	mA	
Maximum power dissipation at	PT	785	mW	SOP
Ta = 25°C (in still air)* ³		500		TSSOP
Storage temperature	Tstg	–65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. This value is limited to 5.5 V maximum.

3. The maximum package power dissipation was calculated using a junction temperature of 150°C.



Recommended Operating Conditions

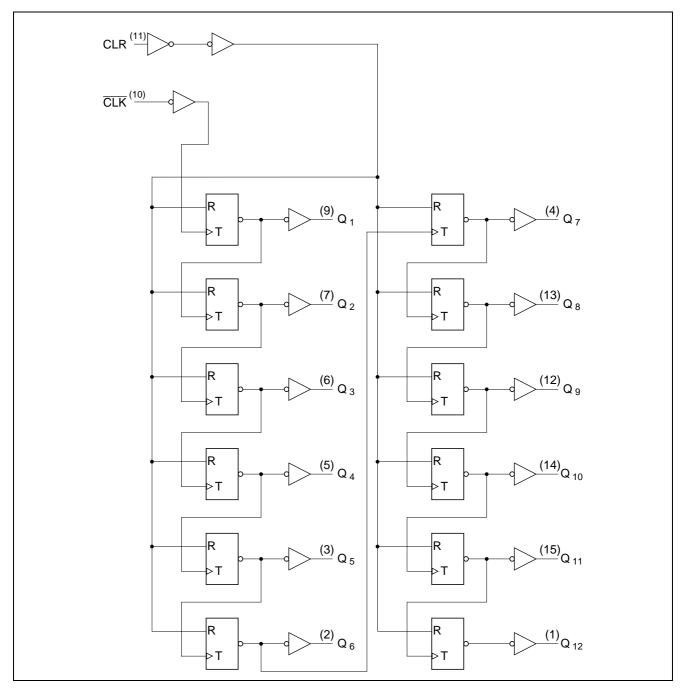
ltem	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V _{CC}	2.0	5.5	V	
Input voltage range	VI	0	5.5	V	
Output voltage range	Vo	0	V _{CC}	V	H or L
Output current	I _{OH}	_	-50	μA	V _{CC} = 2.0 V
		_	-2	mA	V_{CC} = 2.3 to 2.7 V
		_	6		V _{CC} = 3.0 to 3.6 V
		_	-12		V_{CC} = 4.5 to 5.5 V
	I _{OL}	_	50	μA	V _{CC} = 2.0 V
		_	2	mA	V_{CC} = 2.3 to 2.7 V
		_	6		V _{CC} = 3.0 to 3.6 V
		_	12		V_{CC} = 4.5 to 5.5 V
Input transition rise or fall rate	$\Delta t / \Delta v$	0	200	ns/V	V_{CC} = 2.3 to 2.7 V
		0	100		V _{CC} = 3.0 to 3.6 V
		0	20		V_{CC} = 4.5 to 5.5 V
Operating free-air temperature	Та	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

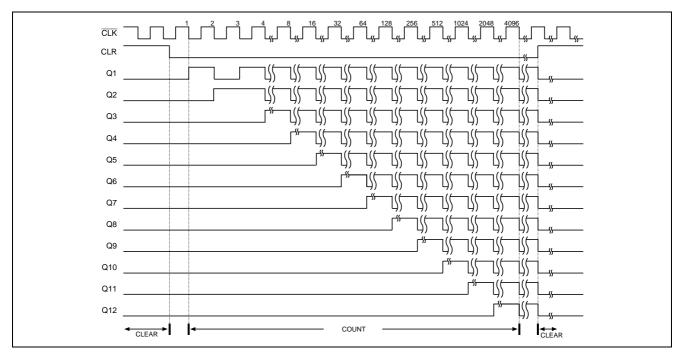


HD74LV4040A

Logic Diagram



Timing Diagram



DC Electrical Characteristics

							$Ta = -40$ to $85^{\circ}C$
Item	Symbol	V _{cc} (V)*	Min	Тур	Max	Unit	Test Conditions
Input voltage	VIH	2.0	1.5			V	
		2.3 to 2.7	V _{CC} ×0.7			_	
		3.0 to 3.6	V _{CC} ×0.7	_		_	
		4.5 to 5.5	V _{CC} ×0.7	_	—	_	
	VIL	2.0	_	_	0.5	_	
		2.3 to 2.7	_	_	. V _{CC} ×0.3	_	
		3.0 to 3.6	—	—	V _{CC} ×0.3	_	
		4.5 to 5.5	—		. V _{CC} ×0.3		
Output voltage	V _{OH}	Min to Max	V _{CC} -0.1			V	I _{OH} = –50 μA
		2.3	2.0				I _{OH} = -2 mA
		3.0	2.48				I _{ОН} = –6 mA
		4.5	3.8				I _{OH} = -12 mA
	V _{OL}	Min to Max	_		0.1		I _{OL} = 50 μA
		2.3	_		0.4		I _{OL} = 2 mA
		3.0	—		0.44		I _{OL} = 6 mA
		4.5	—		0.55		I _{OL} = 12 mA
Input current	I _{IN}	0 to 5.5	—		±1	μA	V_{IN} = 5.5 V or GND
Quiescent supply current	I _{CC}	5.5	_	_	20	μA	$V_{IN} = V_{CC}$ or GND, $I_0 = 0$
Output leakage current	I _{OFF}	0	_		5	μA	V_1 or V_0 = 0 to 5.5 V
Input capacitance	CIN	3.3		3.7		pF	$V_{I} = V_{CC} \text{ or } GND$

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

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Switching Characteristics

								$V_{CC}=2.5\pm0.2$			
		Ta =	25°C		Ta = –4	40 to 85°C		Test	FROM	то	
ltem	Symbol	Min	Тур	Max	Min	Max	Unit	Conditions	(Input)	(Output)	
Maximum	f _{max}	50	90	_	40	_	MHz	C _L = 15 pF			
clock frequency		30	60	_	25	—		C _L = 50 pF			
Propagation	t _{PLH} /t _{PHL}	_	10.0	16.0	1.0	18.3	ns	C _L = 15 pF	CLK	Q ₁	
delay time		_	12.7	19.6	1.0	22.2		C _L = 50 pF			
	t _{PHL}		9.9	15.4	1.0	17.5		C _L = 15 pF	CLR	_	
		_	11.8	18.0	1.0	20.4		C _L = 50 pF			
Propagation delay time skew	Δt_{pd}	_	3.0	5.5	_	6.3	ns	C _L = 50 pF	Q _n	Q _n +1	
Setup time	t _{su}	7.0		_	7.0	—	ns		CLR inac CLK ↓	ctive before	
Pulse width	t _w	7.0	_		7.0	_	ns		CLK high	n or low	
		7.0	_		7.0				CLR high	า	

		Ta =	25°C		Ta = –	40 to 85°C		Test	FROM	то
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Conditions	(Input)	(Output)
Maximum	f _{max}	75	140	_	70	—	MHz	C _L = 15 pF		
clock frequency		55	80	—	50	—		C _L = 50 pF		
Propagation	t _{PLH} /t _{PHL}	_	7.5	11.9	1.0	14.0	ns	C _L = 15 pF	CLK	Q1
delay time		_	10.0	15.4	1.0	17.5		C _L = 50 pF		
	t _{PHL}	_	8.3	12.8	1.0	15.0		C _L = 15 pF	CLR	
		_	10.8	16.3	1.0	18.5		C _L = 50 pF		
Propagation delay time skew	Δt_{pd}	_	2.4	4.4	—	5.0	ns	C∟ = 50 pF	Qn	Q _n +1
Setup time	t _{su}	5.0	_	-	5.0	_	ns		$\frac{CLR}{CLK}\downarrow$	ctive before
Pulse width	t _w	5.0	_	_	5.0		ns		CLK high	n or low
		5.0	_		5.0	_	_		CLR high	ı

 $V_{CC}=3.3\pm0.3~V$



Switching Characteristics (Cont.)

								•	$CC = 3.0 \pm 0.3$
	Ta =	25°C		Ta = –4	40 to 85°C		Test	FROM	то
Symbol	Min	Тур	Max	Min	Max	Unit	Conditions	(Input)	(Output)
f _{max}	150	210	_	125	_	MHz	C _L = 15 pF		
	95	125		80	_		C _L = 50 pF		
t _{PLH} /t _{PHL}	_	4.8	7.3	1.0	8.5	ns	C _L = 15 pF	CLK	Q ₁
	_	6.3	9.3	1.0	10.5		C _L = 50 pF		
t _{PHL}		5.6	8.6	1.0	10.0		C _L = 15 pF	CLR	_
	_	7.1	10.6	1.0	12.0		C _L = 50 pF		
Δt_{pd}	_	1.6	3.1	_	3.5	ns	C _L = 50 pF	Q _n	Q _n + 1
t _{su}	5.0			5.0	—	ns		CLR inac CLK ↓	ctive before
t _w	5.0	_	_	5.0	_	ns		CLK high	n or low
	5.0	_	_	5.0	_	_		CLR high	า
	f _{max} t _{PLH} /t _{PHL} t _{PHL} Δt _{pd} t _{SU}	$\begin{array}{c c} \mbox{Symbol} & \mbox{Min} \\ f_{max} & 150 \\ 95 \\ t_{PLH} & \\ \\ t_{PHL} & \\ t_{PHL} & \\ \\ t_{D} \\ t_{D} \\ \Delta t_{pd} & \\ t_{SU} & 5.0 \\ t_{W} & 5.0 \\ \end{array}$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{tabular}{ c c c c } \hline Symbol & \hline Min & Typ & Max \\ \hline f_{max} & 150 & 210 & \\ \hline 95 & 125 & \\ \hline 95 & 125 & \\ \hline 95 & 125 & \\ \hline 0 & & 6.3 & 9.3 \\ \hline t_{PLH} & & 6.3 & 9.3 \\ \hline t_{PHL} & & 5.6 & 8.6 \\ \hline & 7.1 & 10.6 \\ \hline \Delta t_{pd} & & 1.6 & 3.1 \\ \hline t_{SU} & 5.0 & \\ \hline t_w & 5.0 & & \\ \hline \end{tabular}$	$\begin{array}{ c c c c c c c } \hline Symbol & Min & Typ & Max & Min \\ \hline f_{max} & 150 & 210 & & 125 \\ \hline 95 & 125 & & 80 \\ \hline t_{PLH}/t_{PHL} & & 4.8 & 7.3 & 1.0 \\ \hline t_{PHL} & & 6.3 & 9.3 & 1.0 \\ \hline t_{PHL} & & 5.6 & 8.6 & 1.0 \\ \hline t_{Q} & & 7.1 & 10.6 & 1.0 \\ \hline \Delta t_{pd} & & 1.6 & 3.1 & \\ \hline t_{SU} & 5.0 & & & 5.0 \\ \hline t_w & 5.0 & & & 5.0 \\ \hline \end{array}$	$\begin{array}{ c c c c c c c c } \hline Symbol & \hline Min & Typ & Max & Min & Max \\ \hline f_{max} & 150 & 210 & & 125 & \\ \hline 95 & 125 & & 80 & \\ \hline t_{PLH}/t_{PHL} & & 4.8 & 7.3 & 1.0 & 8.5 \\ \hline & 6.3 & 9.3 & 1.0 & 10.5 \\ \hline t_{PHL} & & 5.6 & 8.6 & 1.0 & 10.0 \\ \hline & 7.1 & 10.6 & 1.0 & 12.0 \\ \hline \Delta t_{pd} & & 1.6 & 3.1 & & 3.5 \\ \hline t_{SU} & 5.0 & & & 5.0 & \\ \hline t_w & 5.0 & & & 5.0 & \\ \hline \end{array}$	$\begin{array}{ c c c c c c c } \hline Symbol & \hline Min & Typ & Max & Min & Max & Unit \\ \hline f_{max} & 150 & 210 & & 125 & & MHz \\ \hline 95 & 125 & & 80 & & \\ \hline t_{PLH}/t_{PHL} & & 4.8 & 7.3 & 1.0 & 8.5 & ns \\ \hline t_{PHL} & & 6.3 & 9.3 & 1.0 & 10.5 & \\ \hline t_{PHL} & & 5.6 & 8.6 & 1.0 & 10.0 & \\ \hline & 7.1 & 10.6 & 1.0 & 12.0 & \\ \hline \Delta t_{pd} & & 1.6 & 3.1 & & 3.5 & ns \\ \hline t_{SU} & 5.0 & & & 5.0 & & ns \\ \hline t_w & 5.0 & & & 5.0 & & ns \\ \hline \end{array}$	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$ \begin{array}{c c c c c c c c c c c c c c c c c c c $

Operating Characteristics

			Ta = 25	5°C			
Item	Symbol	$V_{CC} = (V)$	Min	Тур	Max	Unit	Test Conditions
Power dissipation capacitance	CPD	3.3	_	17.3	_	pF	f = 10 MHz
		5.0	_	19.0	—		

Noise Characteristics

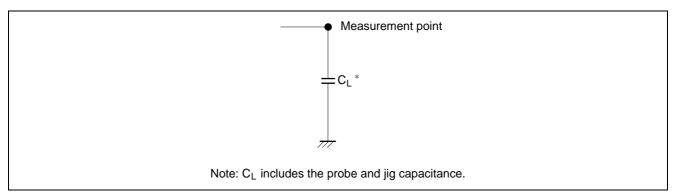
			Ta = 25	5°C			
Item	Symbol	$V_{CC} = (V)$	Min	Min Typ		Unit	Test Conditions
Quiet output, maximum dynamic V _{OL}	V _{OL (P)}	3.3	_	0.4	0.8	V	
Quiet output, minimum dynamic V _{OL}	V _{OL (V)}	3.3	—	-0.5	-0.8	V	
Quiet output, minimum dynamic V _{OH}	$V_{OH(V)}$	3.3	_	3.0	—	V	
High-level dynamic input voltage	V _{IH (D)}	3.3	2.31	—	—	V	
Low-level dynamic input voltage	VIL (D)	3.3	_	—	0.99	V	

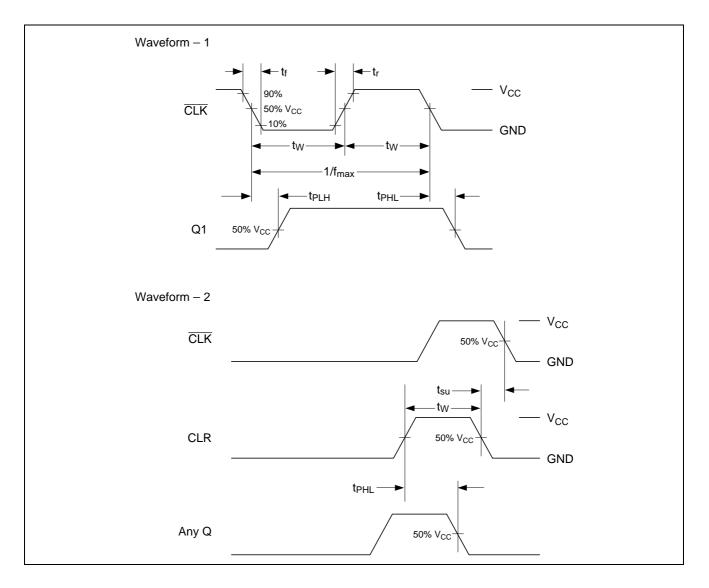
 $C_L = 50 \text{ pF}$

 $C_L = 50 \text{ pF}$

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Test Circuit

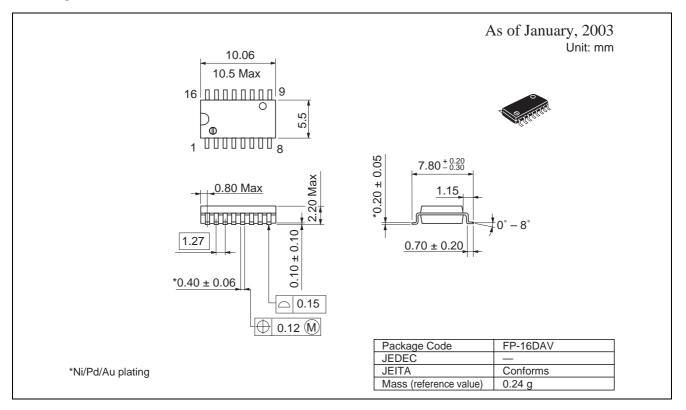


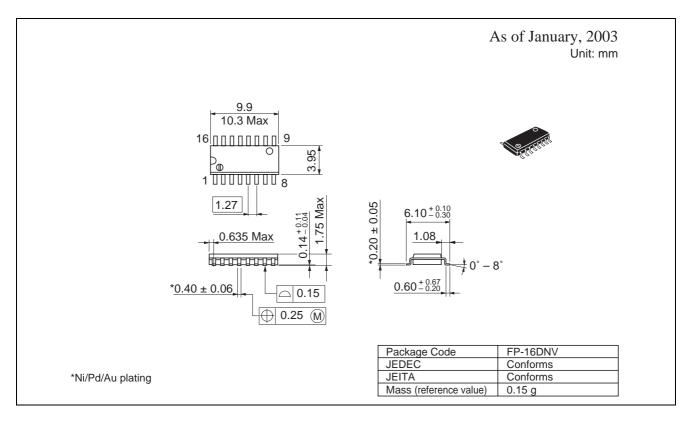


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Package Dimensions

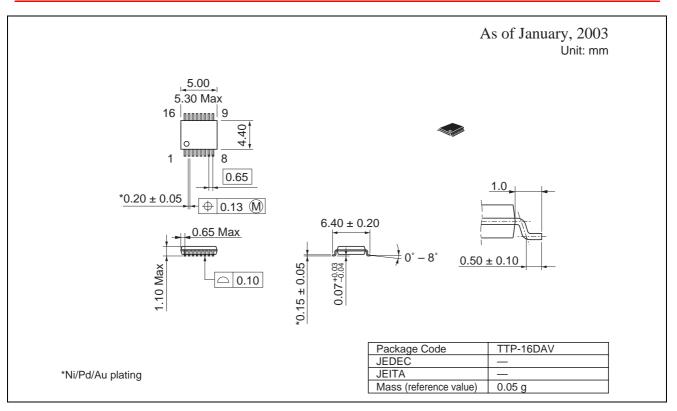




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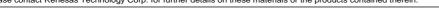


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